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Nozoe, A.; Kotani, H.; Tsujikawa, T.; Yoshida, K.; Furusawa, K.; Kato, M.; Nishimoto, T.; Kume, H.; Kurata, H.; Miyamoto, N.; Kubono, S.; Kanamitsu, M.; Koda, K.; Nakayama, T.; Kouro, Y.; Hosogane, A.; Ajika, N.; Koyashi, K.;

Solid-State Circuits, IEEE Journal of , Volume: 34 , Issue: 11 , Nov. 1999

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